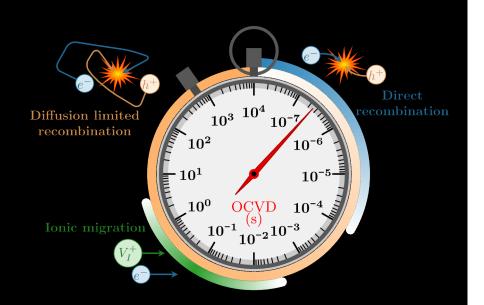
Transient phenomena and ion kinetics in triple-cation perovskites over a wide time range

Vladimir Dyakonov Chair of Experimental Physics VI Julius-Maximilian-University of Würzburg Germany

INSTITUT



Summer School on Future prospects of perovskite based solar cells: 2023-05-15, Khiva, UZ

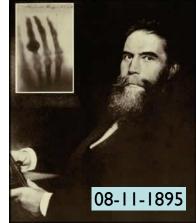


University of Würzburg











- Transient absorption and photoluminescence (TA, TRPL)
 - Probing all absorbing excited states
 - Probing radiative recombination ٠
- Transient microwave conductivity (GHz) and OPTP
- non-contac Probing mobility and lifetime of charge carriers after pulsed excitation

Transient photovoltage (OCVD) and photocurrent

- Probing recombination in solar cells under operating conditions ٠
- Transient conductivity (e.g., Time-of-Flight)
 - Probing transit time of *mobile* charge carriers after pulsed excitation

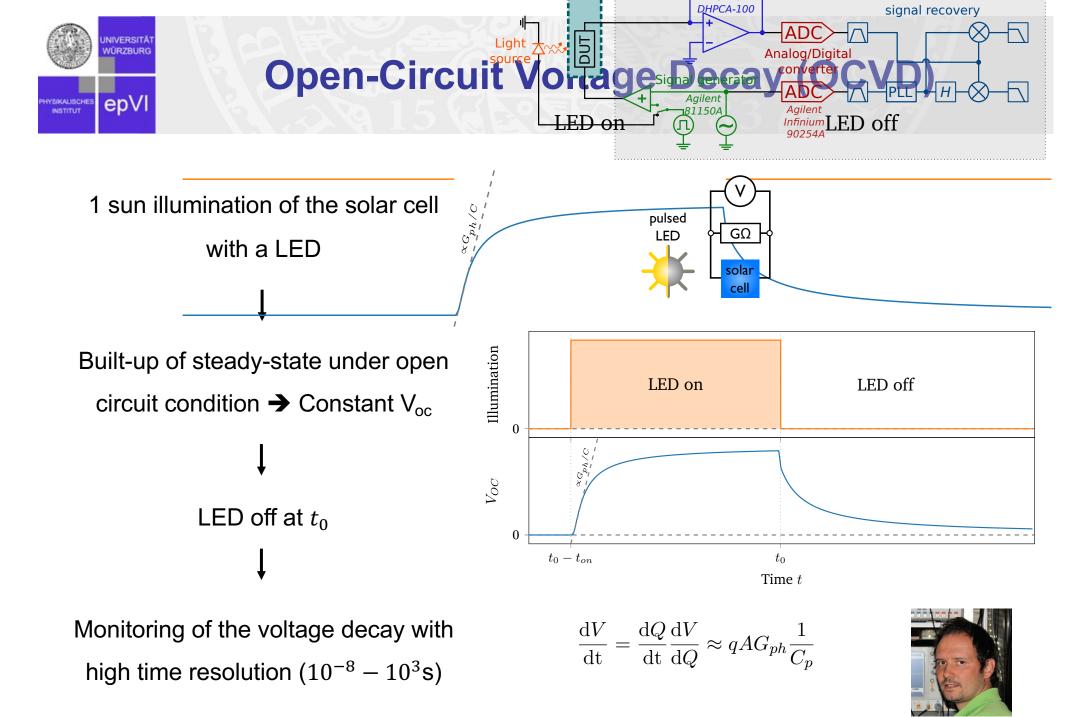
contact



Study of ion migration in PSC using **Open-Circuit Voltage Decay (OCVD)**

Challenges: Coupling between ions and electrons / holes makes the resulting dynamics and transient processes highly non-trivial

A. Baumann, VD et al., APL Mater. 2, 081501 (2014)M. Fischer, VD et al., Sustain. Energy Fuels 5, 3578 (2021)

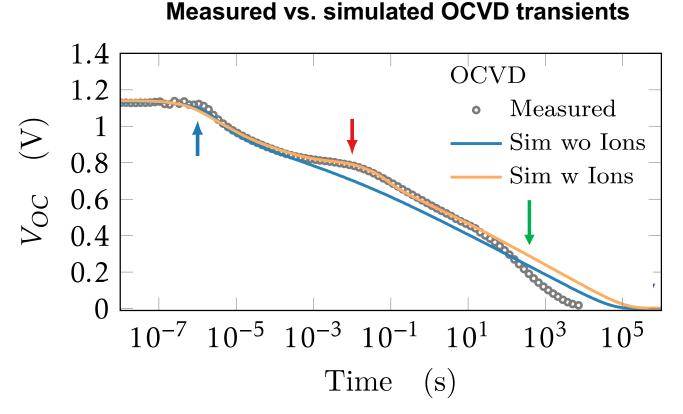


S. Lederhandler and L. Giacoletto, **Proc. IRE** 43, 477 (1955). A. Baumann, VD et al., **APL Mater.** 2, 081501 (2014)

Dr. Andreas Baumann 9



Features of an OCVD transient

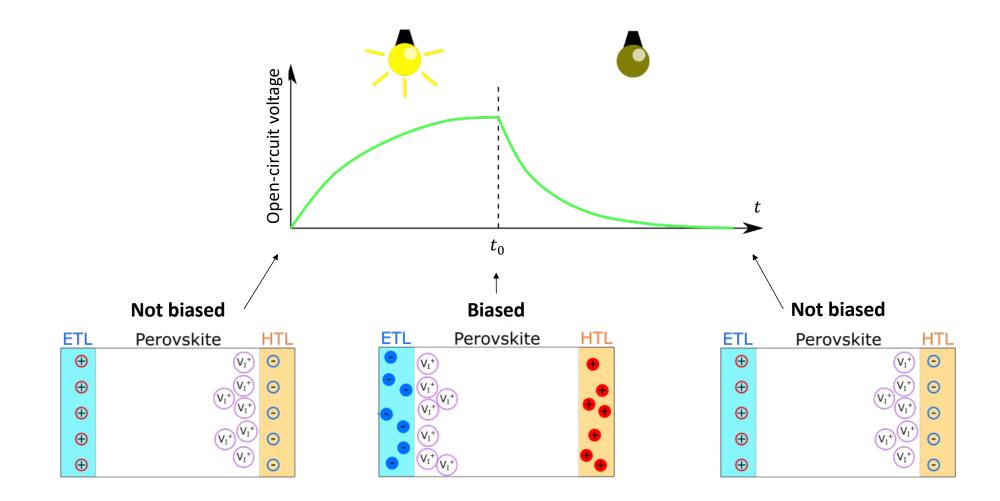


- → Free carrier dynamics ~1-10µs: electron/hole recombination
- \rightarrow Ion redistribution ~1-100ms: slow down V_{oc} decay
- \rightarrow Shunt regime >100s: Leakage currents lead to a faster decay of V_{oc}



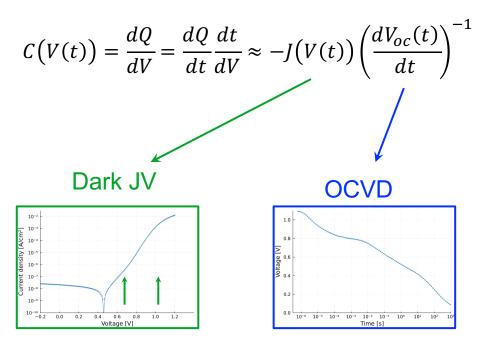
M. Fischer, VD, K. Tvingstedt et al., Sustain. Energy Fuels 5, 3578 (2021)



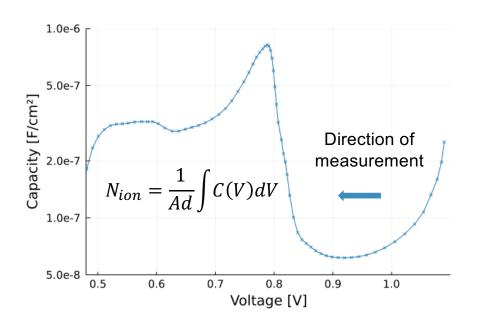




1. Device capacity C(t)



Voltage-resolved device capacity C(V)



2. Total number of ions:

$$Q_{ion} = \int C(V) dV$$

3. Mobile ion concentration:

$$N_{ion} = \frac{Q_{ion}}{A * d}$$



Device capacity C(t):

$$C(V(t)) = \frac{dQ}{dV} = \frac{dQ}{dt}\frac{dt}{dV} \approx -J(V(t))\left(\frac{dV_{oc}(t)}{dt}\right)^{-1}$$

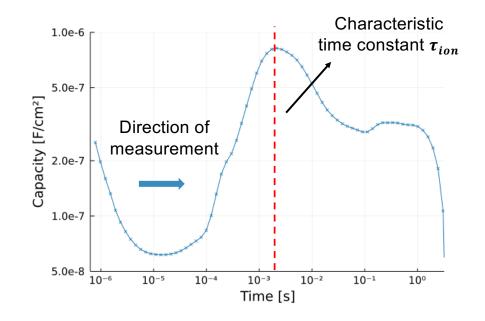
lon diffusivity:

Time-resolved device capacity C(t)

$$D_{ion} = \frac{d}{\tau_{ion}} \sqrt{\frac{\epsilon_P \epsilon_0 k_B T}{q^2 N_{ion}}}$$

lon density:

$$N_{ion} = \frac{1}{Ad} \int C(V) dV$$





Device structure



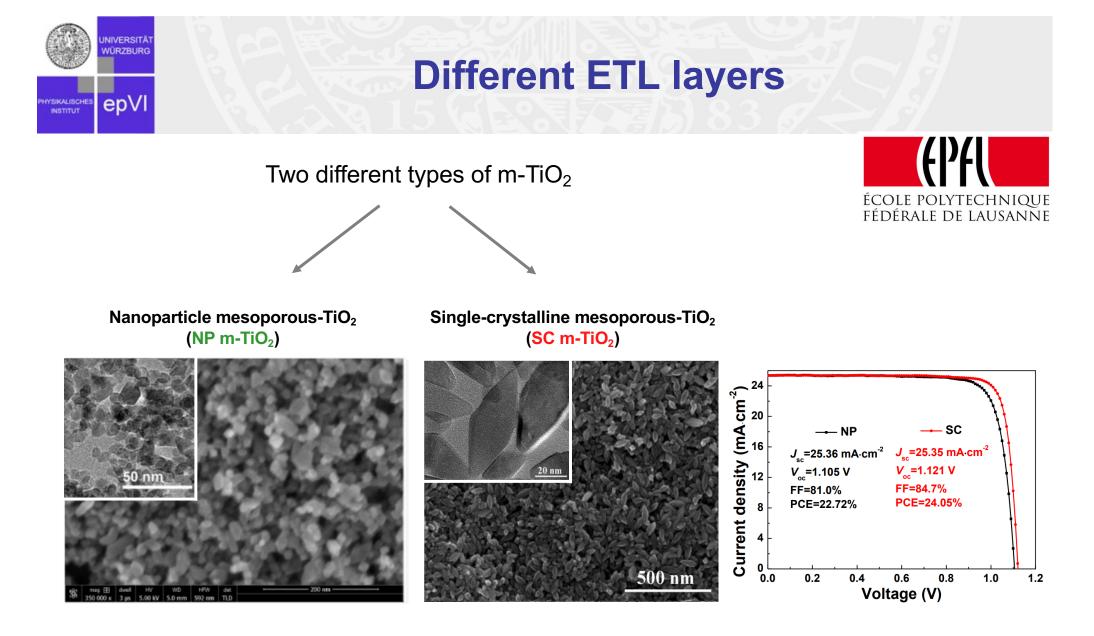
Gold Electrode (\mathbf{V}) Spiro-OMeTAD HTL Passivation layer PEAI Cs_{0.05}MA_{0.05}FA_{0.90}PbI₃ Perovskite mesoporous-TiO₂ ETL compact-TiO₂ Gold Conductive oxide FTO Substrate Glas

Mesoporous n-i-p device

- Triple Cation perovskite composition
- Different types of m-TiO₂ as ETL



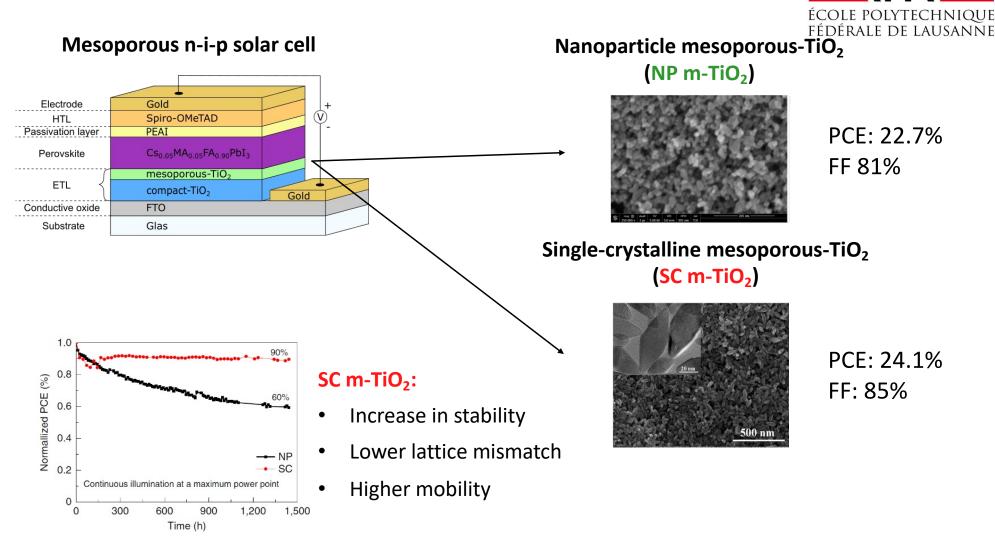
Dr. Yong Ding



PCE: 22% *vs.* 24% FF: 81% *vs.* 84%

Morphology of mesoporous TiO₂ ETL





Y. Ding, VD, MKN et al., Nature Nanotechnology 17, 598 (2022)

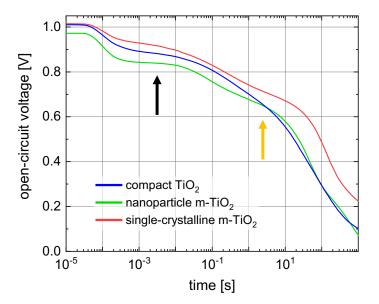
OCVD transients

OCVD transient

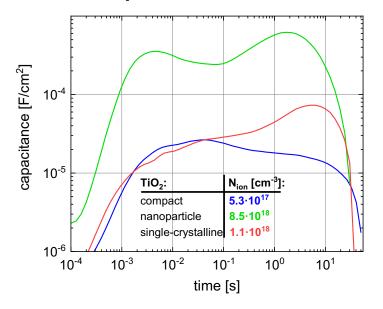
INIVERSITÄ1 WÜRZBURG

epV

YSIKAI ISCHE



Capacitance transient



Device capacity C(V(t)): $C(V(t)) = \frac{dQ}{dV} = \frac{dQ}{dt}\frac{dt}{dV} \approx -J(V(t))\left(\frac{dV_{oc}(t)}{dt}\right)^{-1}$ Dark JV Inverse OCVD

Mobile ion density:

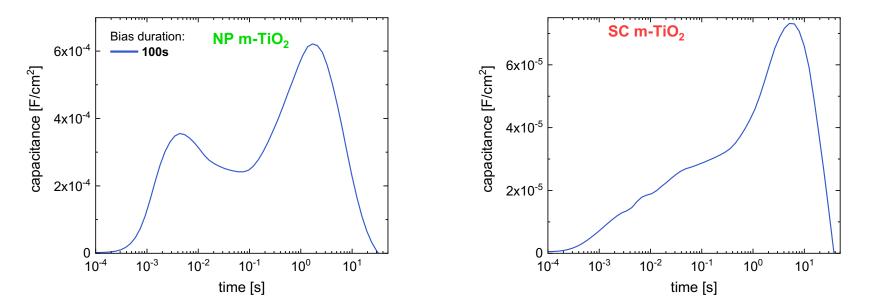
 $N_{ion} = \frac{\int C(V)dV}{A*d}$



Valentin Schmid

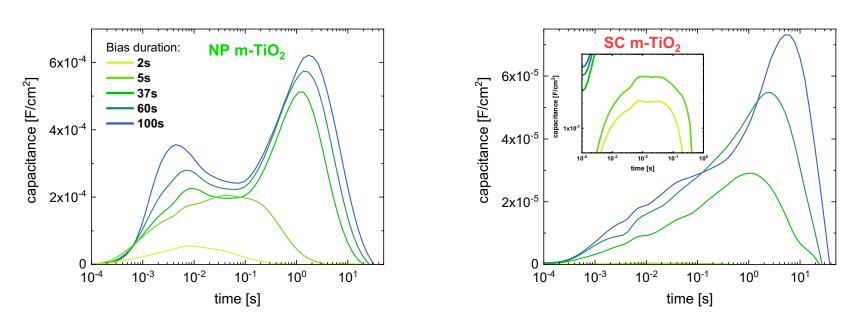






• Different ion kinetics, fast and slow moving ions



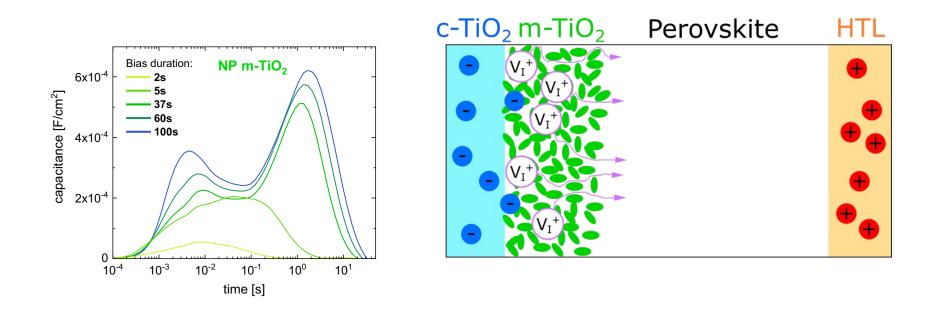


Time-resolved device capacity C(t)

- Different ion kinetics, fast and slow moving ions
- Ionic contribution increases and shifts with increasing bias duration
- The slow moving ions are pronounced in the SC m-TiO₂ device

 \rightarrow mesoporous-TiO₂ slows down mobile ions – but why?





- **During bias:** Mobile ions either accumulate at the interface between m-TiO₂ and perovskite or diffuse into the perovskite-filled pores
- **During decay:** slowed diffusion of mobile ions out of pores

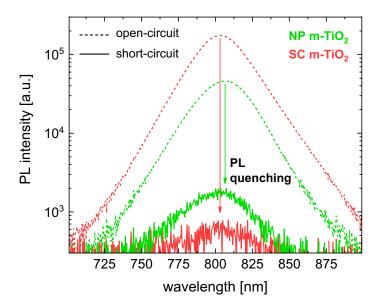


Steady-state PL

INIVERSITÄ1 WÜRZBURG

epV

INSTITUT



• Higher PL quenching between open and short circuit condition

 \rightarrow SC m-TiO₂ reduces the surface recombination at ETL/PVK interface

10⁰ NP m-TiO₂ SC m-TiO₂ norm. PL intensity interface recombination regime 10⁻¹ 10⁻² 150 50 100 200 250 300 350 0

Transient PL

• **t < 50 ns**: extraction in transport layer & interface recombination

time [ns]

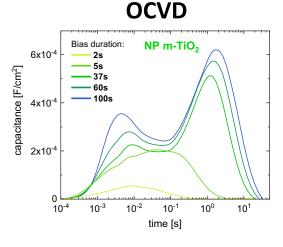
 t > 50 ns: reduced interface recombination



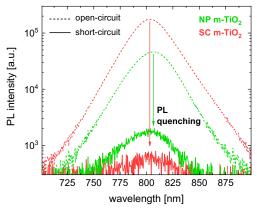
Summary OCVD

Single-crystalline (SC) vs. nanoparticle (NP) m-TiO₂ as ETL

- OCVD enables the study of the kinetics of mobile ions in fully operating PSC
- The morphology of the nanoparticles used for the m-TiO₂ layer influences both ion concentration and diffusivity
- SC m-TiO₂: successfully slows down mobile ions and decreases the ion density in the bulk perovskite
- PL quenching and transient PL reveals a reduced surface recombination at ETL/PVK interface for the SC m-TiO₂









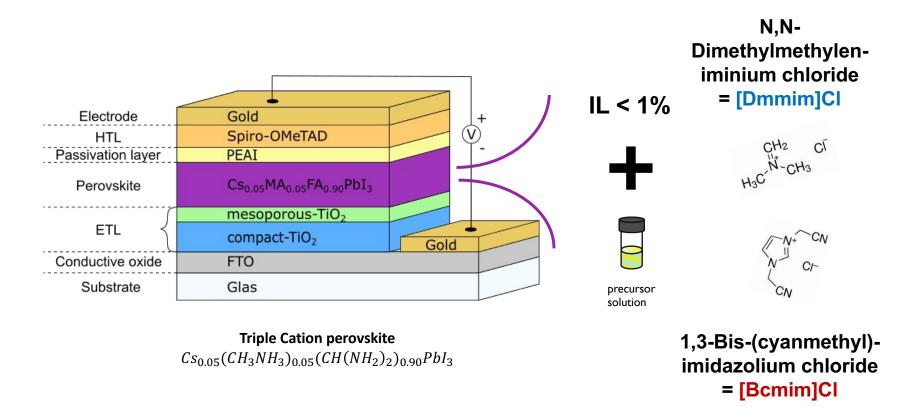
Influence of ionic liquids on charge carrier mobility in triple cation perovskite solar cells

Opportunities: ionic liquids (ILs) tend to improve thermal stability **Challenges**: influence on structural and electronic properties unknown



Triple-cation perovskite films

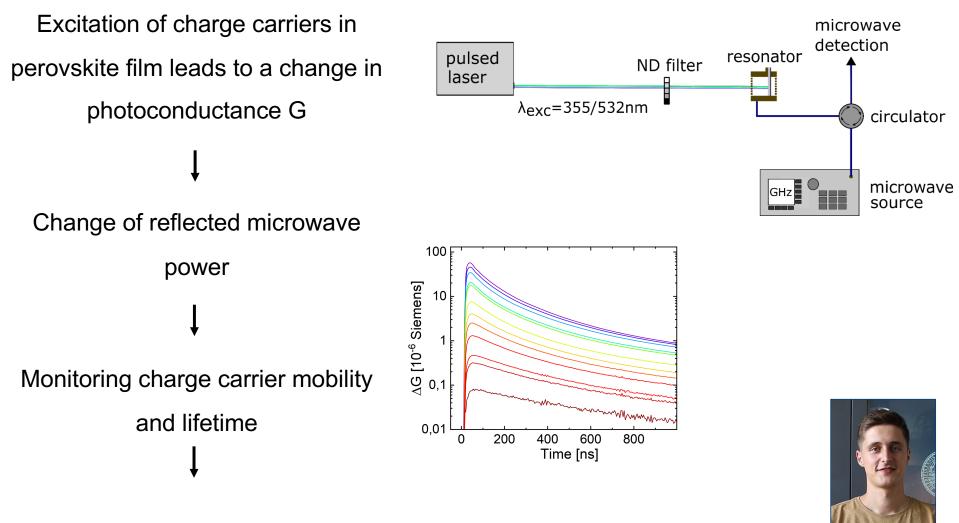
Ionic liquids



- [Dmmim]Cl: Incorporates into the crystal lattice, no influence on the crystallization
- [Bcmim]CI: Deposits on the perovskite surface, improves crystallinity and growth



Time-Resolved Microwave Conductivity (TRMC)



Time resolution few tens of ns

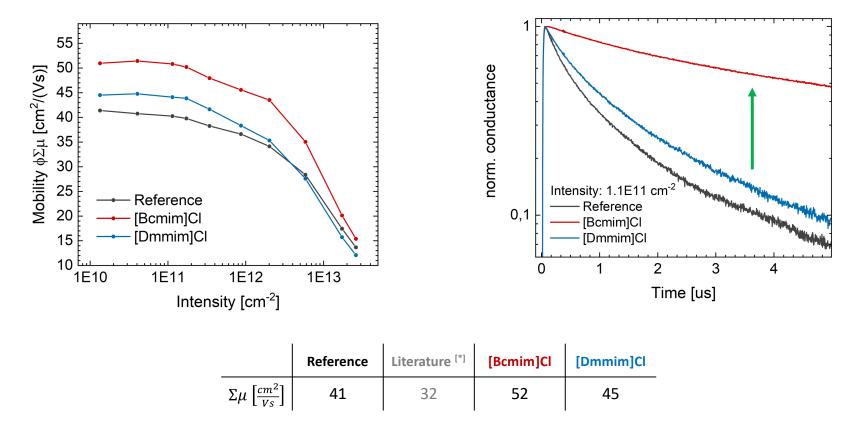
Patrick Dörflinger 33

UNIVERSITÄT WÜRZBURG

Charge Carrier Dynamics

Charge carrier mobility

Charge carrier lifetime

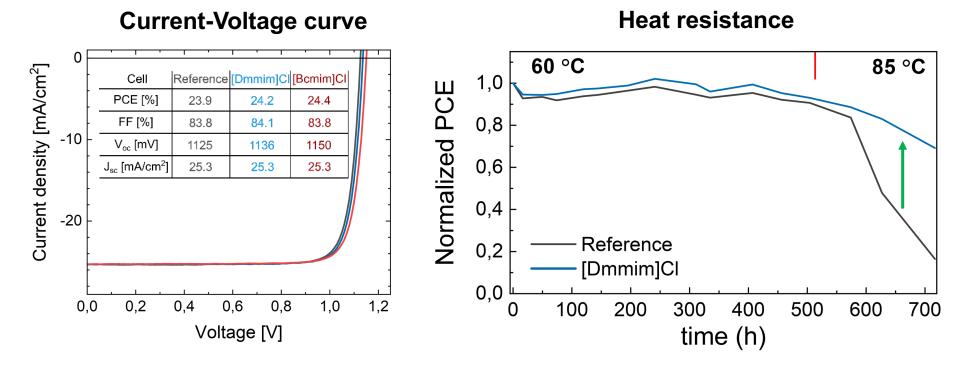


- Increase in charge carrier mobility and lifetime for [Bcmim]Cl
- Minor effects on the charge carrier dynamics for [Dmmim]Cl

[*] H. Hempel, P. Dörflinger, VD et al., Adv. Energy Mater. 12, 2102776 (2022)

Impact of ILs on solar cells



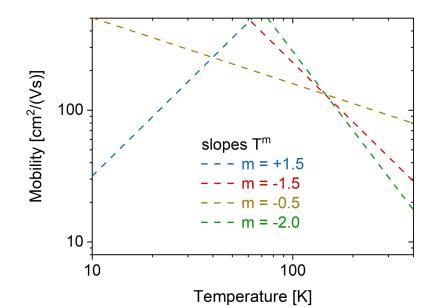


- Highest efficiency (24.4%) for [Bcmim]Cl doped solar cells (24.2% for [Dmmim]Cl)
- Both ionic liquids increase the V_{OC}
- PCE tracking reveals a higher heat resistance for [Dmmim]Cl
- PLQY stable over 100h at 85°C for [Dmmim]Cl, slight decrease for [Bcmim]Cl

Y. Ding, VD, MKN et al., Nature Nanotechnology 17, 598 (2022)



Temperature-dependent mobility



Why measuring temperature dependent mobility?

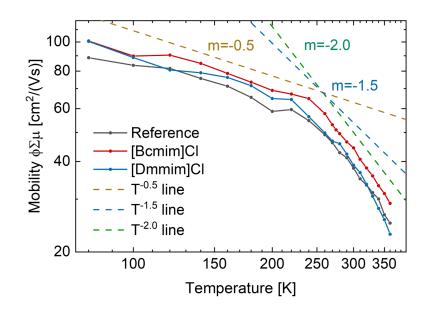
Slope gives information about the **predominating** scattering mechanism!

 $\mu \propto T^m$

- $m = +\frac{3}{2}$: ionized impurity scattering
- $m = -\frac{3}{2}$: acoustic phonon scattering
- $m = -\frac{1}{2}$: LO phonon scattering
- m = -2 : dynamic disorder (Pb-I bonds)
- J. Frost, PRB 96, 195202 (2017) M. Z. Mayers et al., Nano Lett. 18, 8041 (2018)



Temperature-dependent mobility



Why measuring temperature dependent mobility?

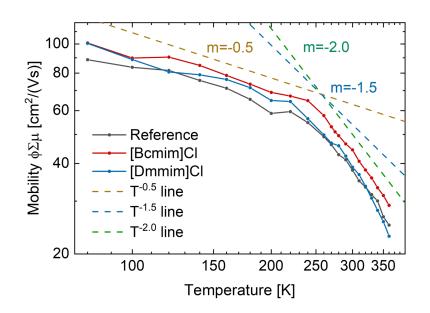
Slope gives information about the **predominating** scattering mechanism!

 $\mu \propto T^m$

- $m = +\frac{3}{2}$: ionized impurity scattering
- $m = -\frac{3}{2}$: acoustic phonon scattering
- $m = -\frac{1}{2}$: LO phonon scattering
- m = -2 : dynamic disorder (Pb-I bonds)
- J. Frost, PRB 96, 195202 (2017) M. Z. Mayers et al., Nano Lett. 18, 8041 (2018)



Temperature-dependent mobility



Why measuring temperature dependent mobility?

Slope gives information about the **predominating** scattering mechanism!

 $\mu \propto T^m$

- T < 260K: scattering dominated by LO phonons
- *T* > 260*K*: scattering dominated by dynamic disorder

→ IL has **no influence** on the predominating scattering mechanisms



Summary TRMC

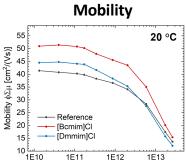
Ionic liquid doped perovskite absorbers:

[Bcmim]Cl doped perovskite:

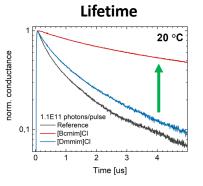
- Aggregates on the grain surface
- Higher crystallinity[***] and film quality
- Increase in mobility and lifetime
- High PCE

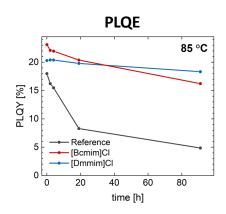
[Dmmim]Cl doped perovskite:

- Incorporates into the crystal lattice
- Minor changes in mobility and lifetime
- Increased heat resistance of the solar cells while maintaining high PCE



Intensity [cm⁻²]





[***] Bin Ding et al., submitted (2022)



Acknowledgements



Valentin Schmid Mathias Fischer Patrick Dörflinger Melina Armer Dr. Kris Tvingstedt Dr. Andreas Baumann

SI Pe

SPP 2196 **DFG** Perovskite Semiconductors: From fundamental properties to devices

DY18/14 DFG-SNF 2019-2025



Prof. Mohammad K. Nazeeruddin Dr. Yong Ding Dr. Bin Ding Dr. Cristina Momblona Prof. Paul Dyson Dr. Zhaofu Fei